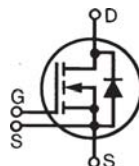


## HiPerFET™ Power MOSFET

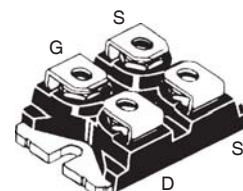
## IXFN180N10

N-Channel Enhancement Mode  
Avalanche Rated  
Fast Intrinsic Rectifier



$$\begin{aligned} V_{DSS} &= 100V \\ I_{D25} &= 180A \\ R_{DS(on)} &\leq 8m\Omega \\ t_{rr} &\leq 250ns \end{aligned}$$

miniBLOC  
E153432



G = Gate      D = Drain  
S = Source

Either Source Terminal S can be used as the Source Terminal or the Kelvin Source (Gate Return) Terminal.

| Symbol     | Test Conditions                                                          | Maximum Ratings |                  |
|------------|--------------------------------------------------------------------------|-----------------|------------------|
| $V_{DSS}$  | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$                          | 100             | V                |
| $V_{DGR}$  | $T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ , $R_{GS} = 1M\Omega$    | 100             | V                |
| $V_{GSS}$  | Continuous                                                               | $\pm 20$        | V                |
| $V_{GSM}$  | Transient                                                                | $\pm 30$        | V                |
| $I_{D25}$  | $T_C = 25^\circ\text{C}$                                                 | 180             | A                |
| $I_{DM}$   | $T_C = 25^\circ\text{C}$ , Pulse Width Limited by $T_{JM}$               | 720             | A                |
| $I_A$      | $T_C = 25^\circ\text{C}$                                                 | 180             | A                |
| $E_{AS}$   | $T_C = 25^\circ\text{C}$                                                 | 3               | J                |
| $dv/dt$    | $I_S \leq I_{DM}$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ\text{C}$ | 5               | V/ns             |
| $P_D$      | $T_C = 25^\circ\text{C}$                                                 | 600             | W                |
| $T_J$      |                                                                          | -55 ... +150    | $^\circ\text{C}$ |
| $T_{JM}$   |                                                                          | 150             | $^\circ\text{C}$ |
| $T_{stg}$  |                                                                          | -55 ... +150    | $^\circ\text{C}$ |
| $V_{ISOL}$ | 50/60 Hz, RMS, $t = 1$ minute                                            | 2500            | V~               |
|            | $I_{ISOL} \leq 1mA$ , $t = 1s$                                           | 3000            | V~               |
| $M_d$      | Mounting Torque for Base Plate                                           | 1.5/13          | Nm/lb.in         |
|            | Terminal Connection Torque                                               | 1.3/11.5        | Nm/lb.in         |
| Weight     |                                                                          | 30              | g                |

| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified) | Characteristic Values |      |                     |
|--------------|---------------------------------------------------------------------------|-----------------------|------|---------------------|
|              |                                                                           | Min.                  | Typ. | Max.                |
| $BV_{DSS}$   | $V_{GS} = 0V$ , $I_D = 3mA$                                               | 100                   |      | V                   |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$ , $I_D = 8mA$                                           | 2.0                   |      | 4.0 V               |
| $I_{GSS}$    | $V_{GS} = \pm 20V$ , $V_{DS} = 0V$                                        |                       |      | $\pm 100$ nA        |
| $I_{DSS}$    | $V_{DS} = V_{DSS}$ , $V_{GS} = 0V$<br>$T_J = 125^\circ\text{C}$           |                       |      | 100 $\mu A$<br>2 mA |
| $R_{DS(on)}$ | $V_{GS} = 10V$ , $I_D = 90A$ , Note 1                                     |                       |      | 8 m $\Omega$        |

### Features

- International Standard Package
- miniBLOC, with Aluminium Nitride Isolation
- Dynamic  $dv/dt$  Rating
- Avalanche Rated
- Fast Intrinsic Rectifier
- Low  $R_{DS(on)}$
- Low Drain-to-Tab Capacitance
- Low Package Inductance

### Advantages

- Easy to Mount
- Space Savings

### Applications

- DC-DC Converters
- Battery Chargers
- Switch-Mode and Resonant-Mode Power Supplies
- Synchronous Rectification
- Low Voltage relays
- DC Chopper
- Temperature and Lighting Controls

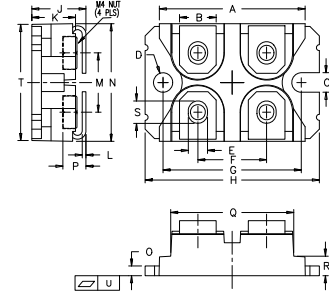
| Symbol       | Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified)                                                             | Characteristic Values |       |                        |
|--------------|---------------------------------------------------------------------------------------------------------------------------------------|-----------------------|-------|------------------------|
|              |                                                                                                                                       | Min.                  | Typ.  | Max.                   |
| $g_{fs}$     | $V_{DS} = 10\text{V}, I_D = 60\text{A}$ , Note 1                                                                                      | 45                    | 76    | S                      |
| $C_{iss}$    | $V_{GS} = 0\text{V}, V_{DS} = 25\text{V}, f = 1\text{MHz}$                                                                            |                       | 10.90 | nF                     |
| $C_{oss}$    |                                                                                                                                       |                       | 3.55  | nF                     |
| $C_{rss}$    |                                                                                                                                       |                       | 1.94  | nF                     |
| $t_{d(on)}$  | <b>Resistive Switching Times</b><br>$V_{GS} = 10\text{V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 90\text{A}$<br>$R_G = 1\Omega$ (External) |                       | 50    | ns                     |
| $t_r$        |                                                                                                                                       |                       | 90    | ns                     |
| $t_{d(off)}$ |                                                                                                                                       |                       | 140   | ns                     |
| $t_f$        |                                                                                                                                       |                       | 65    | ns                     |
| $Q_{g(on)}$  | $V_{GS} = 10\text{V}, V_{DS} = 0.5 \cdot V_{DSS}, I_D = 90\text{A}$                                                                   |                       | 390   | nC                     |
| $Q_{gs}$     |                                                                                                                                       |                       | 55    | nC                     |
| $Q_{gd}$     |                                                                                                                                       |                       | 195   | nC                     |
| $R_{thJC}$   |                                                                                                                                       |                       | 0.05  | $0.21^\circ\text{C/W}$ |
| $R_{thCS}$   |                                                                                                                                       |                       |       | $^\circ\text{C/W}$     |

## Source-Drain Diode

| Symbol   | Test Conditions<br>( $T_J = 25^\circ\text{C}$ Unless Otherwise Specified)                      | Characteristic Values |      |               |
|----------|------------------------------------------------------------------------------------------------|-----------------------|------|---------------|
|          |                                                                                                | Min.                  | Typ. | Max.          |
| $I_S$    | $V_{GS} = 0\text{V}$                                                                           |                       |      | 180 A         |
| $I_{SM}$ | Repetitive, Pulse Width Limited by $T_{JM}$                                                    |                       |      | 720 A         |
| $V_{SD}$ | $I_F = 100\text{A}, V_{GS} = 0\text{V}$ , Note 1                                               |                       |      | 1.5 V         |
| $t_{rr}$ | $I_F = 50\text{A}, -di/dt = 100\text{A}/\mu\text{s}$<br>$V_R = 50\text{V}, V_{GS} = 0\text{V}$ |                       | 1.1  | 250 ns        |
| $Q_{RM}$ |                                                                                                |                       |      | $\mu\text{C}$ |
| $I_{RM}$ |                                                                                                |                       |      | A             |

Note: 1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

## SOT-227B (IXFN) Outline



(M4 screws (4x) supplied)

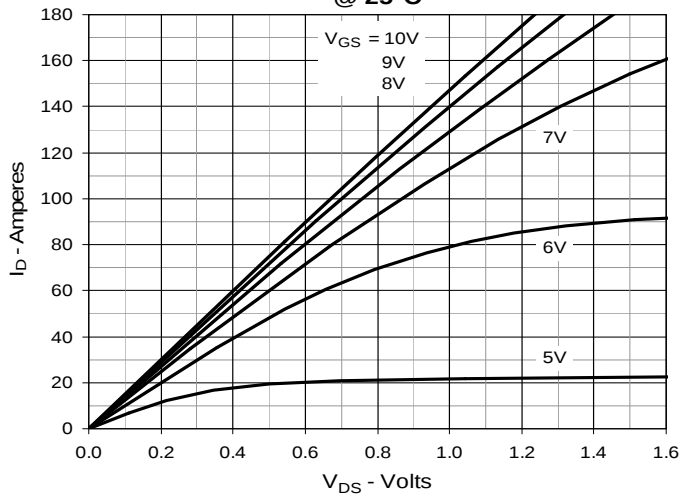
| SYM | INCHES |       | MILLIMETERS |       |
|-----|--------|-------|-------------|-------|
|     | MIN    | MAX   | MIN         | MAX   |
| A   | 1.240  | 1.255 | 31.50       | 31.88 |
| B   | .307   | .323  | 7.80        | 8.20  |
| C   | .161   | .169  | 4.09        | 4.29  |
| D   | .161   | .169  | 4.09        | 4.29  |
| E   | .161   | .169  | 4.09        | 4.29  |
| F   | .587   | .595  | 14.91       | 15.11 |
| G   | 1.186  | 1.193 | 30.12       | 30.30 |
| H   | 1.496  | 1.505 | 38.00       | 38.23 |
| J   | .460   | .481  | 11.68       | 12.22 |
| K   | .351   | .378  | 8.92        | 9.60  |
| L   | .030   | .033  | 0.76        | 0.84  |
| M   | .496   | .506  | 12.60       | 12.85 |
| N   | .990   | 1.001 | 25.15       | 25.42 |
| O   | .078   | .084  | 1.98        | 2.13  |
| P   | .195   | .235  | 4.95        | 5.97  |
| Q   | 1.045  | 1.059 | 26.54       | 26.90 |
| R   | .155   | .174  | 3.94        | 4.42  |
| S   | .186   | .191  | 4.72        | 4.85  |
| T   | .968   | .987  | 24.59       | 25.07 |
| U   | -.002  | .004  | -0.05       | 0.1   |

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

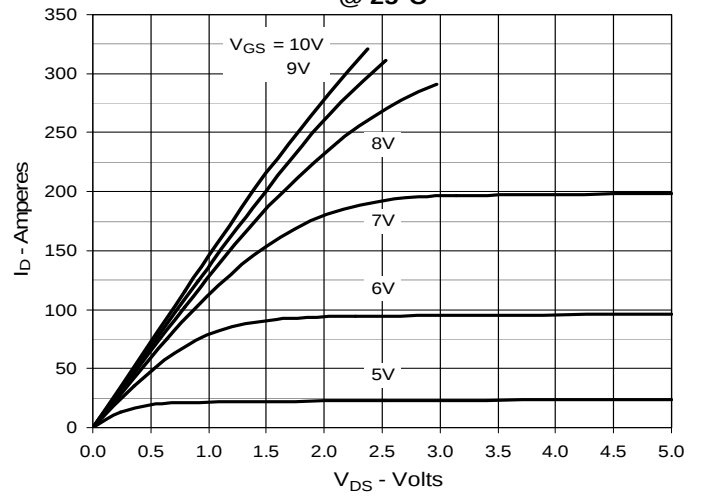
IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

|           |           |           |           |              |              |              |              |              |             |
|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|-------------|
| 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338B2 |
| 4,860,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |             |
| 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |             |

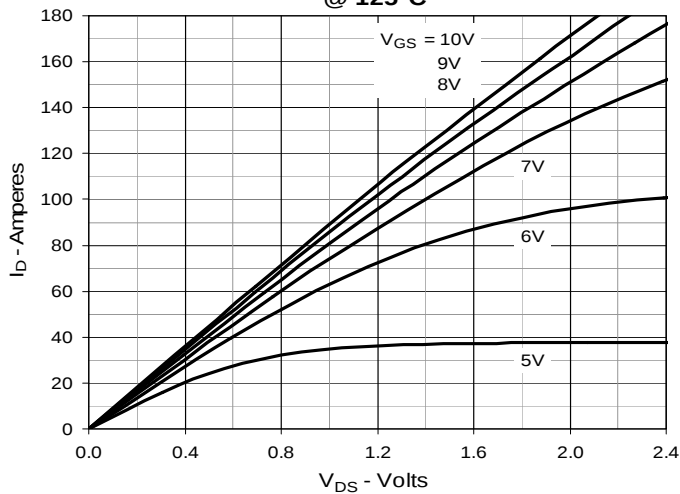
**Fig. 1. Output Characteristics**  
@ 25°C



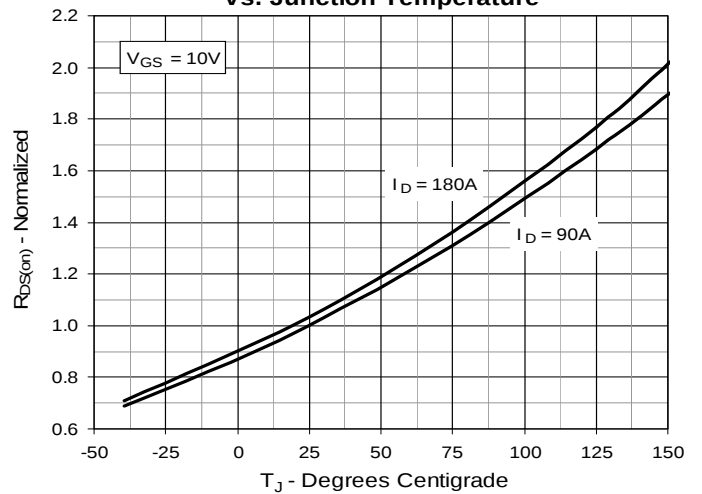
**Fig. 2. Extended Output Characteristics**  
@ 25°C



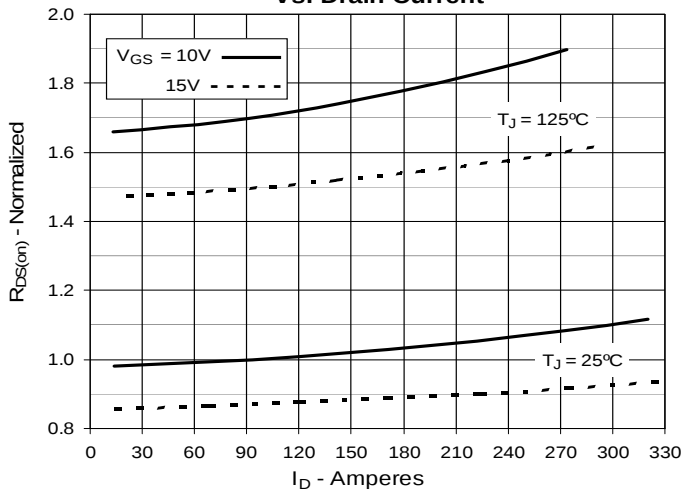
**Fig. 3. Output Characteristics**  
@ 125°C



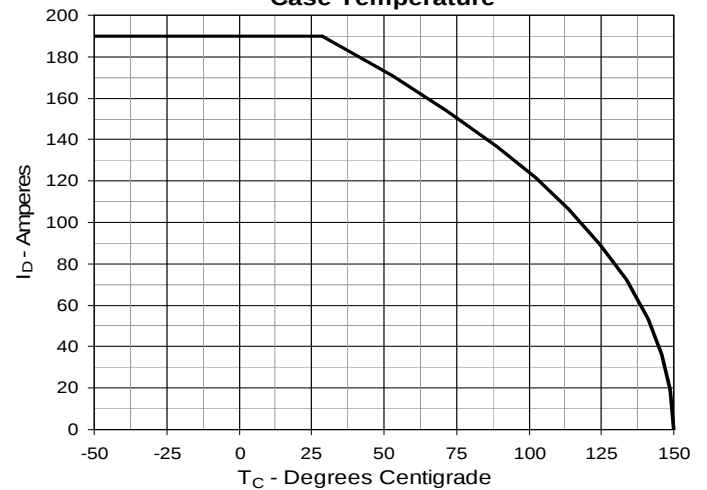
**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 90A$  Value**  
vs. Junction Temperature

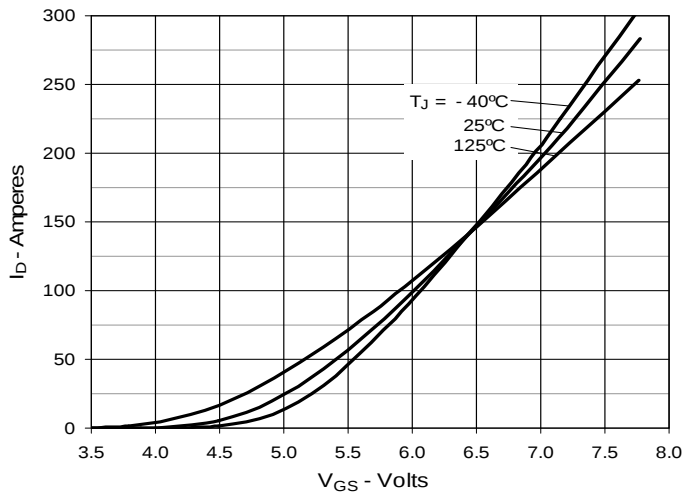
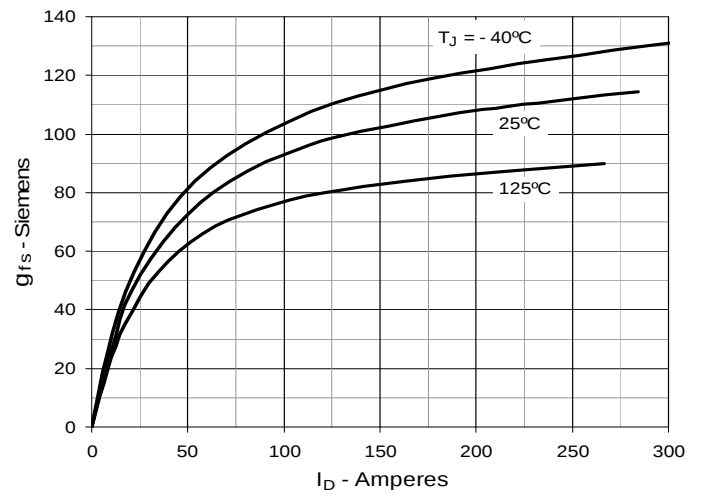
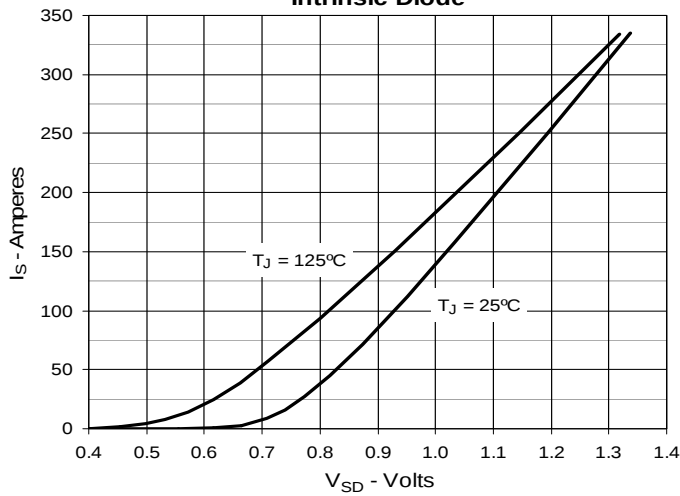
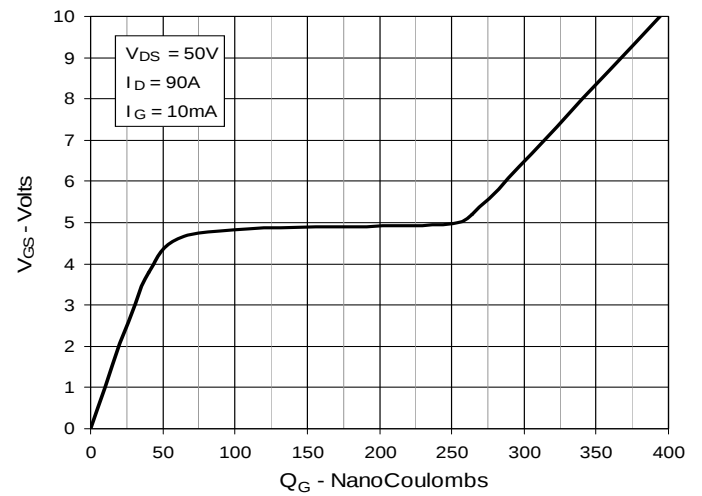
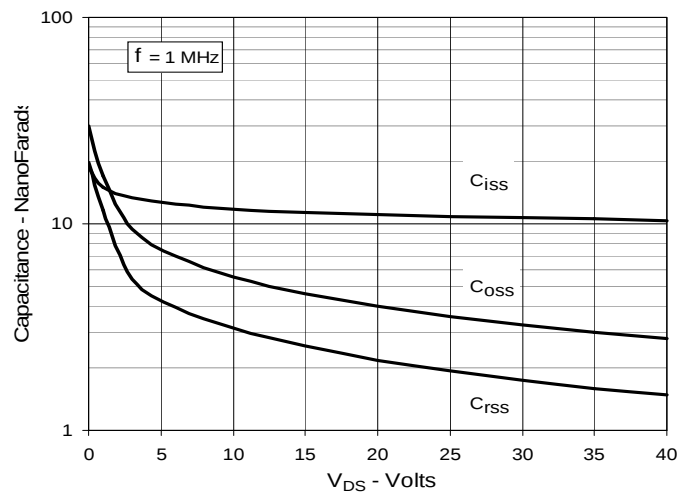
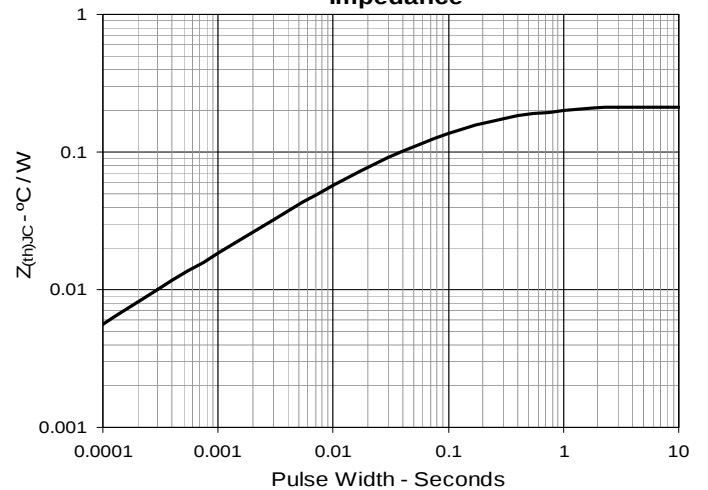


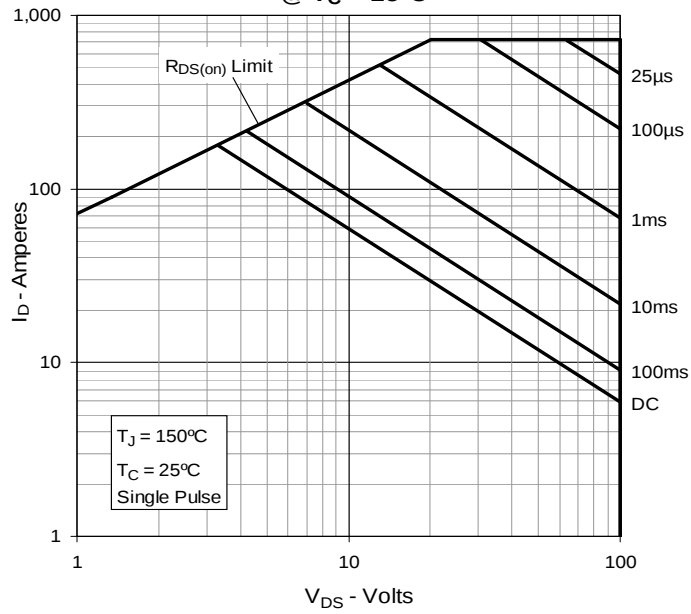
**Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 90A$  Value**  
vs. Drain Current



**Fig. 6. Maximum Drain Current vs.**  
Case Temperature



**Fig. 7. Input Admittance**

**Fig. 8. Transconductance**

**Fig. 9. Forward Voltage Drop of Intrinsic Diode**

**Fig. 10. Gate Charge**

**Fig. 11. Capacitance**

**Fig. 12. Maximum Transient Thermal Impedance**


**Fig. 13. Forward-Bias Safe Operating Area**
**@  $T_C = 25^\circ\text{C}$** 

**Fig. 14. Forward-Bias Safe Operating Area**
**@  $T_C = 75^\circ\text{C}$** 
